# AgPd Termination Conductive Glue Mounting Chip Multilayer Ceramic Capacitors for Automotive GCG1887U2A222JA01\_ (0603, U2J:EIA, 2200pF, DC100V)

\_: packaging code Reference Sheet

# 1.Scope

This product specification is applied to Chip Multilayer Ceramic Capacitors limited to Conductive Glue Mounting used for Automotive Electronic equipment.

# 2.MURATA Part NO. System

(Ex.)	GCG	18	8	7U	2A	222	J	A01	D	
		(1)L/W Dimensions	(2)T Dimensions	(3)Temperature Characteristics	(4)Rated Voltage	(5)Nominal Capacitance	(6)Capacitance Tolerance	(7)Murata's Control Code	(8)Packaging C	Code

# 3. Type & Dimensions



(Unit:mm)

1

(1)-1 L	(1)-2 W	(2) T	е	g
1.6±0.2	0.8±0.1	0.8±0.1	0.2 to 0.5	0.5 min.

# 4.Rated value

(3) Temperature (Public STD Co		(4) Rated	(5) Nominal	(6) Capacitance	Specifications and Test Methods	
Temp. coeff or Cap. Change	. coeff		Capacitance	Tolerance	(Operating Temp. Range)	
-750±120 ppm/°C	25 to 85 °C (25 °C)	DC 100 V	2200 pF	±5 %	-55 to 125 °C	

5.Package

mark	(8) Packaging	Packaging Unit		
D	φ180mm Reel PAPER W8P4	4000 pcs./Reel		
J	φ330mm Reel PAPER W8P4	10000 pcs./Reel		

Product specifications in this catalog are as of Oct.17,2017,and are subject to change or obsolescence without notice. Please consult the approval sheet before ordering.

Please read rating and !Cautions first.

# ■AEC-Q200 Murata Standard Specification and Test Methods

	AEC-Q200 Test Item		Specifi	ication.			AFO COOR Tour Marked				
No			Temperature Compensating Type	High Dielectric Type			AE	C-Q200	Test Method		
1	Pre-and Post-S Electrical Test	Stress			-						
2	High Temperat	ure	The measured and observed charact	teristics should satisfy the	Fix	the capa	acitor to the test s	ubstrate	in the same man	ner and	
	Exposure (Stor	rage)	specifications in the following table.	,	unc	er the sa	ame conditions as	s No.16.			
		Appearance	No marking defects		Set	the cap	acitor for 1000+/-	12hours	at 150+/-3°C.		
					Set	for 24+/	-2hours at room t	empera	ure, then measur	e.	
		Capacitance	Within +/-2.5% or +/-0.25pF	Within +/-12.5%	Ι.	- 141 - 1					
		Change Q or D.F.	(Whichever is larger) 30pF min.: Q≧1000	R7/L8 : 0.05 max.	_				tric constant type 0 °C for 1hour an	d then sit	
	Q or D.F.		30pF max.: Q ≥ 400+20C	R9 : 0.075 max.					Perform the initia		ment.
			C: Nominal Capacitance(pF)	. 0.070 max.							
		I.R.	More than 10000MΩ or 500Ω· F (W	hichever is smaller)	1						
		25°C	R9 : More than $3000 M\Omega$ or 150 $\Omega$ • F	(Whichever is smaller)							
3	Temperature C	cycling	The measured and observed charact	eristics should satisfy the	Fix	the capa	acitor to the test s	ubstrate	in the same man	ner and	
		-	specifications in the following table.		unc	er the sa	ame conditions as	No.16.	Perform the 1000	) cycles	
		Appearance	No marking defects						listed in the follow ture, then measur	•	
		Capacitance	Within +/-2.5% or +/-0.25pF	Within +/-10.0%		C+a	1	1 1	2		
		Change	(Whichever is larger)			Step	Him American	2 Poom	May Operating	A Doom	
		OorDE	20nE min : 0>4000	D7/L9 \\\ \\ \ \ \ 25\/\mir \ \ 0.00	┦	lemp.	Min. Operating Temp.+0/-3	Room Temp.	Max. Operating Temp.+3/-0	Room Temp.	
		Q or D.F.	30pF min. : Q≧1000 30pF max.: Q ≧400+20C	R7/L8 W.V.: 25Vmin.: 0.03 max. W.V.: 16V : 0.05 max			np: -/ *		77: -/ *		
			C: Nominal Capacitance (pF)	R9 : 0.075 max.		Time (min)	15+/-3	1	15+/-3	1	
		I.R.	More than 10000MΩ or $500Ω \cdot F$		۱.	nitial me	asurement for hid	ah dielec	tric constant type		
	25°C		(Whichever is smaller)						0 °C for 1hour an	d then sit	
			,		for 24+/-2hours at room temperature. Perform the initial measurement.						ment.
4	Destructive					EIA-469	).				
5	Physical Analysis Moisture Resis		The measured and observed charact	existics should satisfy the	Fi	41			i		
	Wordtare reesis	nance	The measured and observed characteristics should satisfy the specifications in the following table.				ame conditions as		in the same man	ner and	
			3						and humidity (80	%RH to 98	8%RH)
					trea	itment sl	nown below, 10 c	onsecuti	ve times.		
		Appearance	No marking defects		Set	for 24+/	-2hours at room t	empera	ure, then measur	e.	
						perature	Humidity	Humidity 80∼98%	Humidity 80~989		
		0	Wishing / 2 00/ / 0 20-5	M/M: / 40 50/		°C) 70	90~98%	<del>, , ,</del> , ,	90~98%	90~98%	
		Capacitance Change	Within +/-3.0% or +/-0.30pF (Whichever is larger)	Within +/-12.5%		65		ЬШ			
		Orlange	(Willchever is larger)			55		$\Box$			
		Q or D.F.	30pF min. : Q≧350	R7/L8: 0.05 max.		45 40		$\square$			
			10pF and over, 30pF and below:	R9 : 0.075 max.		35		$\square$			
			Q≧275+5C/2			25	+10	HY			
			10pF max.: Q ≧200+10C			15	- 2	℃			
			C: Nominal Capacitance(pF)			5 1			+		
						0 Init	ial measuremt	$\longrightarrow$			
	I.R.		More than 10000MO, or 5000 • F (W	hichever is smaller\			ial measuremt				
		I.R. 25°C	More than 10000MΩ or 500Ω· F (W R9 : More than 3000MΩ or 150 Ω· F	,		0 5-5-10	lal méasuremt		cle 24hours	10 20 21 22 22	
			, and the second	,		0 5-5-10	1 1 1 1 1 1 1 1 1 1 1 2 3 4 5 6 7		cle 24hours 12 13 14 15 16 17 18 Hours	19 20 21 22 23	3 24
			, and the second	,	. 1	0 -5 -10	asurement for hig	gh dielec	12 13 14 15 16 17 18  Hours  tric constant type		3 24
			, and the second	,	· I	o -5 -10 L o nitial me	asurement for hig	gh dielec	12 13 14 15 16 17 18  → Hours  tric constant type  0 °C for 1hour an	d then sit	
9	Dioced Livery	25°C	R9 : More than 3000M $\Omega$ or 150 $\Omega$ - F	F (Whichever is smaller)	• I Per for	o -5 -10 initial me form a h	asurement for hig eat treatment at o ours at room temp	gh dielec 150+0/-1	12 13 14 15 16 17 18  Hours  tric constant type 0 °C for 1hour an  Perform the initia	d then sit	
6	Biased Humidit	25°C	$\mbox{R9}:\mbox{More than }3000\mbox{M}\Omega$ or $150~\mbox{\Omega}$ . F	F (Whichever is smaller)	• I Per for	o -5 -10 initial me form a h 24+/-2hc	asurement for hig eat treatment at o ours at room temp acitor to the test s	gh dielection of the strate of	12 13 14 15 16 17 18  → Hours  tric constant type  0 °C for 1hour an	d then sit	
6	Biased Humidi	25°C	R9 : More than 3000M $\Omega$ or 150 $\Omega$ - F	F (Whichever is smaller)	• I Per for Fix unc	onitial me form a h 24+/-2hc the capa	asurement for hig eat treatment at o burs at room temp acitor to the test s ame conditions as	gh dielection of the service of the	12 13 14 15 16 17 18  Hours  tric constant type 0 °C for 1hour an  Perform the initia	d then sit Il measure ner and	
6	Biased Humidit	25°C	$R9:More than 3000M\Omega$ or $150~\Omega \cdot F$ The measured and observed charact specifications in the following table.	F (Whichever is smaller)	Per for Fix unc	onitial me form a h 24+/-2hc the capa er the saly the ra	asurement for hig eat treatment at ' ours at room temp acitor to the test s ame conditions at ted voltage and 1	gh dielection of the control of the	12 13 14 15 16 17 18  Hours tric constant type 0 °C for 1 hour an Perform the initia in the same man	d then sit Il measure ner and resister)	ment.
6	Biased Humidit	25°C	$R9:More than 3000M\Omega$ or $150~\Omega \cdot F$ The measured and observed charact specifications in the following table.	F (Whichever is smaller)	Per for Fix und	nitial me form a h 24+/-2hc the capa er the sa oly the ra 5+/-3°C	asurement for highest treatment at a course at room templacitor to the test some conditions as ted voltage and 1 and 80%RH to 8:	gh dielec 150+0/-1 perature. ubstrate s No.16. 1.3+0.2/-	12 13 14 15 16 17 18  Hours  Hours  O °C for 1 hour an  Perform the initia in the same man	d then sit Il measure ner and resister) /-12hours.	ment.
6	Biased Humidii	25°C ty Appearance	R9 : More than 3000M $\Omega$ or 150 $\Omega$ · F The measured and observed charact specifications in the following table. No marking defects	(Whichever is smaller)	Per for Fix unco	onitial me form a h 24+/-2hc the capa er the sally the ra 5+/-3°C move an	asurement for highest treatment at a course at room templacitor to the test some conditions as ted voltage and 1 and 80%RH to 8:	gh dielection of the second of	12 13 14 15 16 17 18  Hours  Hours  O °C for 1 hour an  Perform the initia in the same man  OVdc (add 6.8kΩ  umidity for 1000+  com temperature,	d then sit Il measure ner and resister) /-12hours.	ment.
6	Biased Humidii	ty  Appearance Capacitance	R9 : More than 3000MΩ or 150 Ω • F  The measured and observed charact specifications in the following table.  No marking defects  Within +/-3.0% or +/-0.30pF (Whichever is larger)  30pF and over: Q≧200	reristics should satisfy the  Within +/-12.5%  R7/L8: 0.05 max.	Per for Fix uncompatition App at 8	onitial me form a h 24+/-2hc the capa er the sapely the ra 55+/-3°C move an e charge/	asurement for highest treatment at 4 purs at room templacitor to the test some conditions as ted voltage and 1 and 80%RH to 8 d set for 24+/-2hd/discharge current	gh dielect 150+0/-1 perature. ubstrate s No.16. 1.3+0.2/- 5%RH hours at ro	12 13 14 15 16 17 18  Hours  Hours  O °C for 1hour an  Perform the initia in the same man  0Vdc (add 6.8kΩ  umidity for 1000+  com temperature,  than 50mA.	d then sit Il measure ner and resister) /-12hours.	ment.
6	Biased Humidi	ty  Appearance  Capacitance Change	R9 : More than 3000MΩ or 150 Ω • F  The measured and observed charact specifications in the following table.  No marking defects  Within +/-3.0% or +/-0.30pF (Whichever is larger)  30pF and over: Q≥200  30pF and below: Q≥100+10C/3	reristics should satisfy the  Within +/-12.5%	Per for Fix unc App at & Ree The	onitial me form a h 24+/-2hc the capa er the sally the ra 5+/-3°C move an e charge/	asurement for highest treatment at 4 purs at room templacitor to the test some conditions as ted voltage and 1 and 80%RH to 8 d set for 24+/-2ho discharge current asurement for highest treatment for highest treatment for highest asurement for highest treatment for highest treatment for highest treatment for highest as the formal for highest treatment for high treatment for highest free free free free free free free fre	gh dielection of the last of t	12 13 14 15 16 17 18  Hours  Hours  Tric constant type 0 °C for 1hour an Perform the initia in the same man 0Vdc (add 6.8kΩ umidity for 1000+ com temperature, than 50mA.	d then sit il measurei ner and resister) /-12hours. then meas	ment.
6	Biased Humidit	ty Appearance Capacitance Change Q or D.F.	R9 : More than 3000MΩ or 150 Ω • F  The measured and observed charact specifications in the following table.  No marking defects  Within +/-3.0% or +/-0.30pF (Whichever is larger)  30pF and over: Q≧200  30pF and below: Q≧100+10C/3 C: Nominal Capacitance(pF)	reristics should satisfy the  Within +/-12.5%  R7/L8: 0.05 max.	Per for Fix unc App at 8 Rei The	onitial me form a h 24+/-2hc the capa er the sably the ra 5+/-3°C move an er charge, mittal me form a h	asurement for highest treatment at dispurs at room templacitor to the test some conditions as ted voltage and 1 and 80%RH to 8 diset for 24+/-2holdischarge current asurement for highest treatment at dispurse at treatment	gh dielection of the least of t	12 13 14 15 16 17 18  Hours  Hours  Tric constant type 0 °C for 1hour an Perform the initia in the same man 0Vdc (add 6.8kΩ umidity for 1000+ com temperature, than 50mA.	d then sit Il measurei ner and resister) /-12hours. then meas	ment.
6	Biased Humidit	ty  Appearance  Capacitance Change	R9 : More than 3000MΩ or 150 Ω • F  The measured and observed charact specifications in the following table.  No marking defects  Within +/-3.0% or +/-0.30pF (Whichever is larger)  30pF and over: Q≥200  30pF and below: Q≥100+10C/3	reristics should satisfy the  Within +/-12.5%  R7/L8: 0.05 max.	Per for Fix unc App at 8 Rei The	onitial me form a h 24+/-2hc the capa er the sably the ra 5+/-3°C move an er charge, mittal me form a h	asurement for highest treatment at dispurs at room templacitor to the test some conditions as ted voltage and 1 and 80%RH to 8 diset for 24+/-2holdischarge current asurement for highest treatment at dispurse at treatment	gh dielection of the least of t	12 13 14 15 16 17 18  Hours  Hours  Tric constant type 0 °C for 1hour an Perform the initia in the same man 0Vdc (add 6.8kΩ umidity for 1000+ com temperature, than 50mA.	d then sit Il measurei ner and resister) /-12hours. then meas	ment.

			Spec	ification.				
ю	AEC-Q200	0 Test Item	Temperature Compensating Type	High Dielectric Type	-	AEC-Q200 T	est Method	
7	Operational Life	e	The measured and observed char	acteristics should satisfy the	Fix the capacit	or to the test substrate in	the same manner and	
			specifications in the following table	l	under the sam	e conditions as No.16.		
		Appearance	No marking defects		Apply 150% of temp.+/-3°C.	the rated voltage for 100	00+/-12 hours at max. operating	
		Capacitance	Within +/-3.0% or +/-0.30pF	Within +/-12.5%	Set for 24+/-2h	nours at room temperatur	e, then measure.	
		Change	(Whichever is larger)		The charge/dis	scharge current is less that	an 50mA.	
		Q or D.F.	30pF min. : Q≧350	R7/L8 : 0.05 max.				
			10pF and over, 30pF and below:	R9 : 0.075 max.		rement for high dielectric		
			Q≧275+5C/2			-	ating temp. +/-3°C for 1hour	
			10pF max.: Q ≧200+10C		and then let sit	for 24+/-2hours at room	temperature,then measure.	
		I.R.	C: Nominal Capacitance(pF)					
		25°C	More than $1,000M\Omega$ or $50\Omega \cdot F$ (Whichever is smaller)					
	External Visual		,		Visual inspecti	on		
	External visual	'	TWO defects of apriormalities	No defects or abnormalities		on		
	Physical Dimer	nsion	Within the specified dimensions	Using Measuri	ng instrument of dimension	on.		
)	Resistance to	Appearance	No marking defects			202 Method 215		
	Solvents				Solvent 1:1;	part (by volume) of isopro	ppyl alcohol	
		Capacitance	Within the specified initial value.		3 p	parts (by volume) of mine	ral spirits	
					Solvent 2 : Te	rpene defluxer		
		Q or D.F.	Within the specified initial value.		Solvent 3 : 42 parts (by volume) of water			
					1part (by volume) of propylene glycol monomethyl ether			
		I.R.	More than 10000MΩ or 500Ω •F		1 part (by )	volume) of monoethanola	mine	
		25°C						
+			(Whichever is smaller)  No marking defects		Eiv the consoit	or to the test substrate in	the came manner and	
	Shock	Appearance	No marking defects				Title Same manner and	
	SHOCK	Capacitance	Within the specified initial value.		same conditions as No.16.  Three shocks in each direction should be applied a		on applied along 2 mutually	
		Capacitarice	Within the specified initial value.			axes of the test specimer		
		Q or D.F.	Within the specified initial value.		1	test pulse should be Half-		
		Q OI D.I .	Within the specified initial value.		· ·	•		
		I.R.			duration .0.5iii	s, peak value. 1500g and	velocity change: 4.7m/s.	
		25°C	More than 10000MΩ or $500Ω \cdot F$					
,	Vibration	Appearance	(Whichever is smaller)  No marking defects		Fix the capacit	or to the test substrate in	the same manner and	
	Vibration	Арреагапсе	No marking defects		Fix the capacitor to the test substrate in the same manner and same conditions as No.16.			
		Capacitance	Within the specified initial value.		The capacitor	should be subjected to a	simple harmonic motion having	
					a total amplitue	de of 1.5mm, the frequen	cy being varied uniformly	
Į		Q or D.F.	Within the specified initial value.		between the a	pproximate limits of 10Hz	z and 2000Hz.	
					The frequency	range, from 10Hz to 200	0Hz and return to 10Hz,	
Į		I.R.	More than $10000M\Omega$ or $500\Omega$ •F		should be trav	ersed in approximately 20	0 minutes.	
		25°C	(Whichever is smaller)		This motion sh	ould be applied for 12 cy	cles in each 3 mutually	
					perpendicular	directions (total of 36 time	es).	
			1				the same manner and	
3	Thermal Shock	(	The measured and observed char	acteristics should satisfy the	Fix the capacit	or to the test substrate in		
3	Thermal Shock	1	specifications in the following table	•	under the sam	e conditions as No.16.		
	Thermal Shock	Appearance		•	under the sam Perform the 30	e conditions as No.16. 00 cycles according to the	e two heat treatments listed	
	Thermal Shock	Appearance	specifications in the following table No marking defects		under the sam Perform the 30 in the following	e conditions as No.16. 00 cycles according to the g table(Maximum transfer	time is 20seconds).	
	Thermal Shock	Appearance Capacitance	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF	•	under the sam Perform the 30 in the following	e conditions as No.16. 00 cycles according to the	time is 20seconds).	
	Thermal Shock	Appearance	specifications in the following table No marking defects		under the sam Perform the 30 in the following	e conditions as No.16. 00 cycles according to the g table(Maximum transfer	time is 20seconds).	
8	Thermal Shock	Appearance Capacitance Change	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)	Within +/-10.0%	under the sam Perform the 30 in the following Set for 24+/-2h	e conditions as No.16.  O cycles according to the gable (Maximum transfer nours at room temperatur	time is 20seconds).	
3	Thermal Shock	Appearance Capacitance	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)  30pF min. : Q≥1000	Within +/-10.0%  R7/L8 : W.V.: 25V min.: 0.025 max.*	under the sam Perform the 30 in the following Set for 24+/-2t	e conditions as No.16. 00 cycles according to the pable (Maximum transfer nours at room temperatur  1  Min. Operating Temp.+0/-3	time is 20seconds). e, then measure.  2  Max. Operating Temp.+3/-0	
3	Thermal Shock	Appearance Capacitance Change	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)  30pF min.: Q≧1000 30pF max.: Q≧400+20C	Within +/-10.0%  R7/L8 : W.V.: 25V min.: 0.025 max.* *GCG21BL81H104K: 0.03 max.	under the sam Perform the 30 in the following Set for 24+/-2t Step Temp.(°C)	e conditions as No.16. 00 cycles according to the grable (Maximum transfer nours at room temperatur	time is 20seconds). re, then measure.	
	Thermal Shock	Appearance Capacitance Change	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)  30pF min. : Q≥1000	Within +/-10.0%  R7/L8 : W.V.: 25V min.: 0.025 max.*  *GCG21BL81H104K: 0.03 max.  W.V.: 16V : 0.035 max.	under the sam Perform the 30 in the following Set for 24+/-2t Step Temp.(°C) Time	e conditions as No.16. 00 cycles according to the pable (Maximum transfer nours at room temperatur  1  Min. Operating Temp.+0/-3	time is 20seconds). e, then measure.  2 Max. Operating Temp.+3/-0	
	Thermal Shock	Appearance Capacitance Change	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)  30pF min.: Q≧1000 30pF max.: Q≧400+20C	Within +/-10.0%  R7/L8 : W.V.: 25V min.: 0.025 max.* *GCG21BL81H104K: 0.03 max.	under the sam Perform the 30 in the following Set for 24+/-2t Step Temp.(°C) Time (min)	e conditions as No.16. 00 cycles according to the pable (Maximum transfer nours at room temperatur  1 Min. Operating Temp.+0/-3 15+/-3	time is 20seconds). te, then measure.  2 Max. Operating Temp.+3/-0 15+/-3	
	Thermal Shock	Appearance Capacitance Change Q or D.F.	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)  30pF min.: Q≥1000 30pF max.: Q≥400+20C C: Nominal Capacitance(pF)	Within +/-10.0%  R7/L8 : W.V.: 25V min.: 0.025 max.*  *GCG21BL81H104K: 0.03 max.  W.V.: 16V : 0.035 max.	under the sam Perform the 30 in the following Set for 24+/-2t Step Temp.(°C) Time (min)	e conditions as No.16. 00 cycles according to the pable (Maximum transfer nours at room temperatur  1 Min. Operating Temp.+0/-3 15+/-3	time is 20seconds).  e, then measure.  2  Max. Operating Temp.+3/-0  15+/-3  c constant type	
	Thermal Shock	Appearance Capacitance Change	specifications in the following table No marking defects  Within +/-2.5% or +/-0.25pF (Whichever is larger)  30pF min.: Q≧1000 30pF max.: Q≧400+20C	Within +/-10.0%  R7/L8 : W.V.: 25V min.: 0.025 max.*  *GCG21BL81H104K: 0.03 max.  W.V.: 16V : 0.035 max.	under the sam Perform the 30 in the following Set for 24+/-2t Step Temp.(°C) Time (min)  Initial meas Perform a hea	e conditions as No.16. 00 cycles according to the pable (Maximum transfer nours at room temperatur  1 Min. Operating Temp.+0/-3 15+/-3  urement for high dielectrit treatment at 150+0/-10	time is 20seconds).  e, then measure.  2  Max. Operating Temp.+3/-0  15+/-3	

# ■AEC-Q200 Murata Standard Specification and Test Methods

			Specifi	ication.					
No	AEC-Q	200 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method				
14	ESD	Appearance	No marking defects		Per AEC-Q200-002				
		Capacitance	Within the specified initial value.						
		Q or D.F.	Within the specified initial value.						
		I.R.	More than $10000M\Omega$ or $500\Omega \cdot F$						
		25℃	(Whichever is smaller)						
15	Electrical Chatacteri-	Appearance	No defects or abnormalities		Visual inspection.				
	zation	Capacitance	Shown in Rated value.		The capacitance/Q/D.F. should be measured at 25°C at the frequency and voltage shown in the table.				
		Q or D.F.	30pF min. : Q≧1000 30pF max.: Q≧400+20C C: Nominal Capacitance(pF)	R7/L8: W.V.: 25Vmin.: 0.025 max. W.V.: 16V : 0.035 max. R9: 0.075 max.	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$				
		I.R. 25°C	More than 100000MΩ or 1000Ω • F (Whichever is smaller)	More than $10000M\Omega$ or $500\Omega \cdot F$ (Whichever is smaller)	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 125°C(for Δ C/7U/R7)/ 150°C (for 5G/L8/R9) within 2 minutes of charging.				
		I.R. 125°C	More than 10000M $\Omega$ or 50 $\Omega$ •F (Whichever is smaller)	More than 1000MΩ or 10Ω∙F (Whichever is smaller)	The charge/discharge current is less than 50mA.				
		I.R. 150°C	More than 10000MΩ or 100Ω • F (Whichever is smaller)	More than 1000MΩ or 1Ω•F (Whichever is smaller)					
		Dielectric Strength	No failure		No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 second to 5 seconds.  The charge/discharge current is less than 50mA.				
16	Terminal Strength	Appearance	No marking defects		Mount the capacitor on the test substrate in Fig.1 using a conductive glue (HEREAUS"PC3000").				
		Capacitance	Within the specified initial value.		The conductive glue is hardened at 140°C for 30 minites.  Then apply *shear tension in parallel with the test substrate for 60 seconds.				
		Q or D.F.	Within the specified initial value.		*Show in the table 1				
		I.R. 25°C	More than 10000M $\Omega$ or 500 $\Omega$ •F (Whichever is smaller)		Series         Share Tension           GCG15         2.0N           GCG18         2.7N           GCG21         4.9N           GCG31         6.9N           GCG32         12.6N           Table. 1				
					Ag Pd electrode  C Alumina  b a a				
					Series         a         b         c           GCG15         0.4         1.5         0.5           GCG18         1.0         3.0         1.2           GCG21         1.2         4.0         1.65           GCG31         2.2         5.0         2.0           GCG32         2.2         5.0         2.9           Fig. 1         (in mm)				

# ■AEC-Q200 Murata Standard Specification and Test Methods

	Spec	ification.	
No AEC-Q200 Test Item	Temperature Compensating Type	High Dielectric Type	AEC-Q200 Test Method
17 Beam Load Test	Chip thickness :  < Chip L dimension : 3.2mm mim. : Chip thickness <	> > 0.5mm rank : 20N = 0.5mm rank : 8N	Place the capacitor in the beam load fixture as Fig 2.  Apply a force.  < Chip Length: 2.5mm max. >  Iron Board  < Chip Length: 3.2mm min. >  Fig.2  Speed supplied the Stress Load: 0.5mm/s.
18 Capacitance Temperature Characteristics	Nominal values of the temperature coefficient is shown in Rated value.  But, the Capacitance Change under Reference Temp. is shown in Table A.  Capacitance Drift Within +/-0.2% or +/-0.05pF (Whichever is larger.)	R7: Within +/-15%  (-55°C to +125°C)  L8: Within +/-15%  (-55°C to +125°C)  Within +15/-40%  (+125°C to +150°C)  R9: Within +/-15%  (-55°C to +150°C)	The capacitance change should be measured after 5 minutes at each specified temp. stage.  Capacitance value as a reference is the value in step 3.  (1)Temperature Compensating Type The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1,3 and 5 by the cap. value in step 3.    Step   Temperature(°C)     1

# Table A Capacitance Change between at Reference Temp. and at each Temp. (%)

Char.	-55		-3	30	-10		
Char.	Max.	Min.	Max.	Min.	Max.	Min.	
5C/5G	0.58	-0.24	0.40	-0.17	0.25	-0.11	
7U	8.78	5.04	6.04	3.47	3.84	2.21	

JEMCGS-06205 5

# 1.Tape Carrier Packaging(Packaging Code:D/E/W/F/L/J/K)

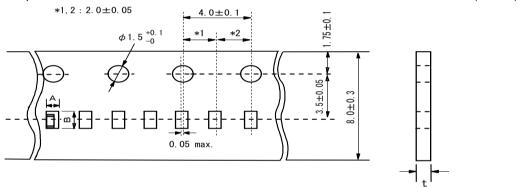
# 1.1 Minimum Quantity(pcs./reel)

			φ180mm reel		φ330mm reel		
	Туре	Pape	· Tape	Plastic Tape	Paper Tape	Plastic Tape	
		Code:D/E	Code:W	Code:L	Code:J/F	Code:K	
GCH15	5 (Dimensions Tolerance:±0.05)	10000(W8P2)	20000(W8P1)		50000(W8P2)		
GCH15	5 (Dimensions Tolerance:±0.2)	10000(W8P2)			40000(W8P2)		
GCH18		4000			10000		
	6	4000			10000		
GCH21	9	4000			10000		
	В			3000		10000	
	9	4000			10000		
GCH31	M			3000		10000	
	С			2000		6000	
GCH32	D/E			1000		4000	

# 1.2 Dimensions of Tape

(1)GCH15 <Paper Tape W8P2 CODE:D/E/J/F>

(in mm)

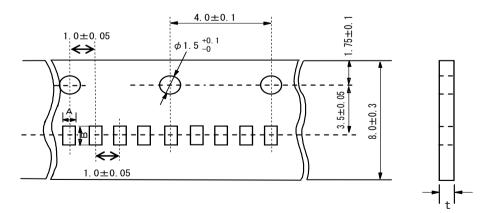


Type		D	imensions(Chi	p)	۸ *2	D *2	<b>+</b>	
Туре		L	W	Т	A *3	БЗ	l l	
GCH15	5	1.0±0.05	0.5±0.05	0.5±0.05	0.65	1.15	0.8 max.	
GCITIS		1.0±0.2	0.5±0.2	0.5±0.2 0.5±0.2 0.75		1.35	U.O IIIAX.	

<sup>\*3</sup> Nominal value

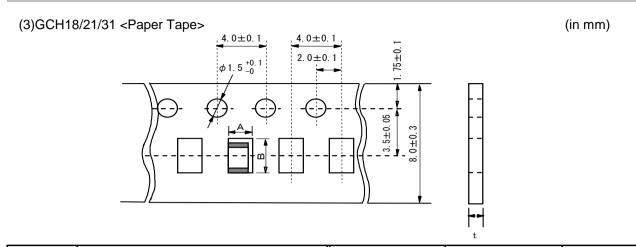
# (2)GCH15 < Paper Tape W8P1 CODE:W>

(in mm)



Type		D	imensions(Chi	p)	۸ *2	D *2	+	
Туре		L	W	Т	A 3	БЭ	· ·	
GCH15	5	1.0±0.05	0.5±0.05	0.5±0.05	0.65	1.15	0.8 max.	

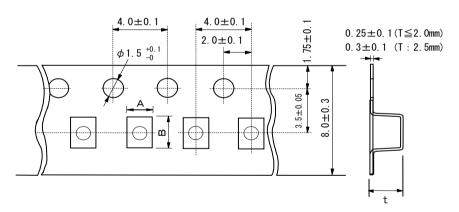
<sup>\*3</sup> Nominal value



Туре		Dimensions(Chip)			۸	R	+
		L	W	T	^	Ь	·
GCH18	8	1.6±0.1	0.8±0.1	0.8±0.1	1.05±0.10	1.85±0.10	
GCH21	6	2.0±0.15	1.25±0.15	0.6±0.1	1.55±0.15	2.30±0.15	1.1 max.
	9			0.85±0.1			
GCH31	9	3.2±0.15	1.6±0.15	0.85±0.1	2.00±0.20	3.60±0.20	

# (4)GCH21/31/32 < Plastic Tape>

(in mm)



Туре		Dimensions(Chip)			А	В	+
		L	W	Т	A	Б	
GCH21	В	2.0±0.15	1.25±0.15	1.25±0.15	1.45±0.20	2.25±0.20	2.0 max.
		2.0±0.2	1.25±0.2	1.25±0.2	1.50±0.20	2.30±0.20	
GCH31	М	3.2±0.15	1.6±0.15	1.15±0.1	1.90±0.20	3.50±0.20	1.7 max.
		3.2±0.2	1.6±0.2	1.15±0.15			
	C	3.2±0.2	1.6±0.2	1.6±0.2			2.5 max.
GCH32	D	3.2±0.3	2.5±0.2	2.0±0.2	2.80±0.20	3.50±0.20	3.0 max.
	Е			2.5±0.2			3.7 max.

Fig.1 Package Chips (in mm)

Fig.2 Dimensions of Reel

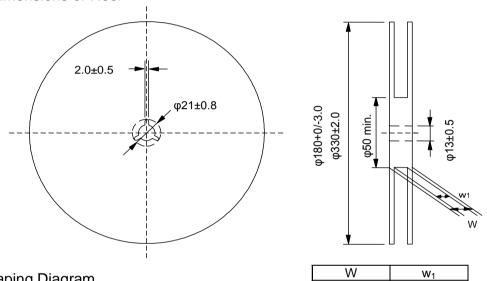
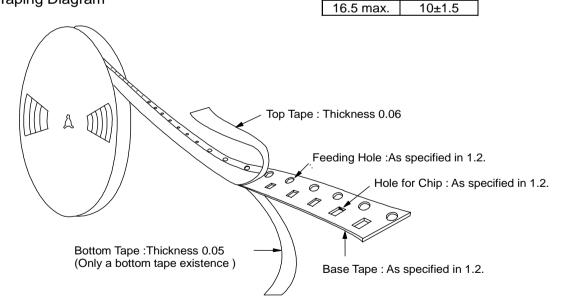
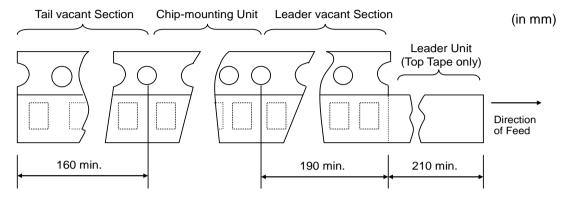


Fig.3 Taping Diagram



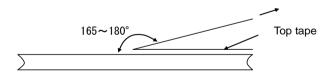
- 1.3 Tapes for capacitors are wound clockwise shown in Fig.3.
  (The sprocket holes are to the right as the tape is pulled toward the user.)
- 1.4 Part of the leader and part of the vacant section are attached as follows.



- 1.5 Accumulate pitch: 10 of sprocket holes pitch =  $40 \pm 0.3$ mm
- 1.6 Chip in the tape is enclosed by top tape and bottom tape as shown in Fig.1.
- 1.7 The top tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.
- 1.8 There are no jointing for top tape and bottom tape.
- 1.9 There are no fuzz in the cavity.
- 1.10 Break down force of top tape : 5N min.

  Break down force of bottom tape : 5N min. (Only a bottom tape existence)
- 1.11 Reel is made by resin and appearance and dimension is shown in Fig 2.

  There are possibly to change the material and dimension due to some impairment.
- 1.12 Peeling off force: 0.1N to 0.6N in the direction as shown below.



1.13 Label that show the customer parts number, our parts number, our company name, inspection number and quantity, will be put in outside of reel.

# ■Limitation of Applications

Please contact us before using our products for the applications listed below which require especially high reliability for the prevention of defects which might directly cause damage to the third party's life, body or property.

- (1) Aircraft equipment (2) Aerospace equipment (3) Undersea equipment (4) Power plant control equipment
- ⑤Medical equipment ⑥Transportation equipment(vehicles,trains,ships,etc.) ⑦Traffic signal equipment
- (MApplication of similar complexity and/or reliability requirements to the applications listed in the above.

# ■ Storage and Operation condition

1. If store the chip multilayer ceramic capacitors in an atmosphere consisting of high temperature or humidity, sulfur or chlorine gases, contaminants attach to the surface of external electrode, and bondability with conductive glue may deteriorate. Do not store the capacitors in an atmosphere consisting of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammoria gas, etc.). Storage environment must be at room temperature of +5°C to +40°C and a relative humidity of 20% to 70%, and use the product within six months after receipt.

In case of packaging, do not open the last wrappend, polyethylene bag, till just before using. After unpacking, immediately reseal, or store in a desiccator containing a desiccant.

- 2. Due to moisture condensation caused by rapid humidity changes, or the photochemical change caused by direct sunlight on the terminal electrodes and/or the resin/epoxy coatings, the bondability with conductive glue and electrical performance may deteriorate. Do not store capacitors under direct sunlight or in high humidity conditions.
- 3. This product is chip monolithic ceramic capacitor limited to conductive glue mounting. Do not apply mounting method other than conductive glue. Flow or reflow soldering can result in a lack of adhesive strength on the outer electrode by poor wettability, which may result in chips breaking loose from the PCB.

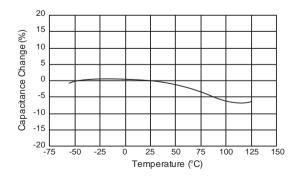
# ■ Rating

# 1.Temperature Dependent Characteristics

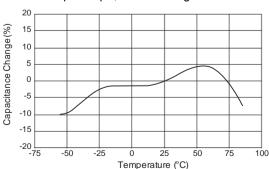
- 1. The electrical characteristics of the capacitor can change with temperature.
- 1-1. For capacitors having larger temperature dependency, the capacitance may change with temperature changes. The following actions are recommended in order to ensure suitable capacitance values.
  - (1) Select a suitable capacitance for the operating temperature range.
  - (2) The capacitance may change within the rated temperature.

    When you use a high dielectric constant type capacitor in a circuit that needs a tight (narrow) capacitance tolerance (e.g., a time-constant circuit), please carefully consider the temperature characteristics, and carefully confirm the various characteristics in actual use conditions and the actual system.

[Example of Temperature Caracteristics X7R(R7)] Sample: 0.1µF, Rated Voltage 50VDC



[Example of Temperature Characteristics X5R(R6)] Sample: 22µF, Rated Voltage 4VDC



### 2.Measurement of Capacitance

- 1. Measure capacitance with the voltage and frequency specified in the product specifications.
- 1-1. The output voltage of the measuring equipment may decrease occasionally when capacitance is high. Please confirm whether a prescribed measured voltage is impressed to the capacitor.
- 1-2. The capacitance values of high dielectric constant type capacitors change depending on the AC voltage applied. Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.

### 3.Applied Voltage

- 1. Do not apply a voltage to the capacitor that exceeds the rated voltage as called out in the specifications.
- 1-1. Applied voltage between the terminals of a capacitor shall be less than or equal to the rated voltage.
  - (1) When AC voltage is superimposed on DC voltage, the zero-to-peak voltage shall not exceed the rated DC voltage. When AC voltage or pulse voltage is applied, the peak-to-peak voltage shall not exceed the rated DC voltage.
  - (2) Abnormal voltages (surge voltage, static electricity, pulse voltage, etc.) shall not exceed the rated DC voltage.



(E: Maximum possible applied voltage.)

1-2. Influence of over voltage

Over voltage that is applied to the capacitor may result in an electrical short circuit caused by the breakdown of the internal dielectric layers.

The time duration until breakdown depends on the applied voltage and the ambient temperature.

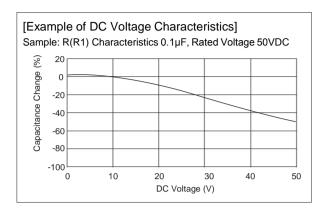
#### 4. Type of Applied Voltage and Self-heating Temperature

- 1. Confirm the operating conditions to make sure that no large current is flowing into the capacitor due to the continuous application of an AC voltage or pulse voltage.
  - When a DC rated voltage product is used in an AC voltage circuit or a pulse voltage circuit, the AC current or pulse current will flow into the capacitor; therefore check the self-heating condition.
  - Please confirm the surface temperature of the capacitor so that the temperature remains within the upper limits of the operating temperature, including the rise in temperature due to self-heating. When the capacitor is used with a high-frequency voltage or pulse voltage, heat may be generated by dielectric loss.
- <Applicable to Rated Voltage of less than 100VDC>
  The load should be contained so that the self-heating of the capacitor body remains below 20°C, when measuring at an ambient temperature of 25°C.



### 5. DC Voltage and AC Voltage Characteristic

- The capacitance value of a high dielectric constant type capacitor changes depending on the DC voltage applied. Please consider the DC voltage characteristics when a capacitor is selected for use in a DC circuit.
- 1-1. The capacitance of ceramic capacitors may change sharply depending on the applied voltage. (See figure) Please confirm the following in order to secure the capacitance.
- (1) Determine whether the capacitance change caused by the applied voltage is within the allowed range.
- (2) In the DC voltage characteristics, the rate of capacitance change becomes larger as voltage increases, even if the applied voltage is below the rated voltage. When a high dielectric constant type capacitor is used in a circuit that requires a tight (narrow) capacitance tolerance (e.g., a time constant circuit), please carefully consider the voltage characteristics, and confirm the various characteristics in the actual operating conditions of the system.
- The capacitance values of high dielectric constant type capacitors changes depending on the AC voltage applied.
   Please consider the AC voltage characteristics when selecting a capacitor to be used in a AC circuit.





# 6. Capacitance Aging

1. The high dielectric constant type capacitors have an Aging characteristic in which the capacitance value decreases with the passage of time. When you use a high dielectric constant type capacitors in a circuit that needs a tight (narrow) capacitance tolerance (e.g., a time-constant circuit), please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics. In addition, check capacitors using your actual appliances at the intended environment and operating conditions.

# [ Example of Change Over Time (Aging characteristics) ]



# 7.Vibration and Shock

- 1. Please confirm the kind of vibration and/or shock, its condition, and any generation of resonance.

  Please mount the capacitor so as not to generate resonance, and do not allow any impact on the terminals.
- Mechanical shock due to being dropped may cause damage or a crack in the dielectric material of the capacitor.Do not use a dropped capacitor because the quality and reliability may be deteriorated.
- 3. When printed circuit boards are piled up or handled, the corner of another printed circuit board should not be allowed to hit the capacitor in order to avoid a crack or other damage to the capacitor.





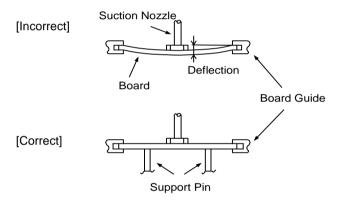
# ■ Mounting

#### 1. Selection of Conductive Adhesive, Mounting Process, and Bonding Strength

1.The acuired bonding strength may change greatly depending on the conductive adhesive to be used. Be sure to confirming the desired performance can be acquired in the assumed monting process with the conductive adhesive to be used.

#### 2. Maintenance of the Mounting (pick and place) Machine

- Make sure that the following excessive forces are not applied to the capacitors.
   Check the mounting in the actual device under actual use conditions ahead of time.
- 1-1. In mounting the capacitors on the printed circuit board, any bending force against them shall be kept to a minimum to prevent them from any damage or cracking. Please take into account the following precautions and recommendations for use in your process.
  - (1) Adjust the lowest position of the pickup nozzle so as not to bend the printed circuit board.



2.Dirt particles and dust accumulated in the suction nozzle and suction mechanism prevent the nozzle from moving smoothly. This creates excessive force on the capacitor during mounting, causing cracked chips. Also, the locating claw, when worn out, imposes uneven forces on the chip when positioning, causing cracked chips. The suction nozzle and the locating claw must be maintained, checked and replaced periodically.

### 3.Moisture proof

1.To prevent the silver electrode migration, keep parts under low moisture condition with resin coating and the equivalent.

#### 4.Coating

- 1. A crack may be caused in the capacitor due to the stress of the thermal contraction of the resin during curing process. The stress is affected by the amount of resin and curing contraction. Select a resin with low curing contraction. The difference in the thermal expansion coefficient between a coating resin or a molding resin and the capacitor may cause the destruction and deterioration of the capacitor such as a crack or peeling, and lead to the deterioration of insulation resistance or dielectric breakdown.
  - Select a resin for which the thermal expansion coefficient is as close to that of the capacitor as possible. A silicone resin can be used as an under-coating to buffer against the stress.
- Select a resin that is less hygroscopic.
   Using hygroscopic resins under high humidity conditions may cause the deterioration of the insulation resistance of a capacitor. An epoxy resin can be used as a less hygroscopic resin.
- 3. The halogen system substance and organic acid are included in coating material, and a chip corrodes by the kind of Coating material. Do not use strong acid type.

## Others

#### 1. Under Operation of Equipment

- 1-1. Do not touch a capacitor directly with bare hands during operation in order to avoid the danger of an electric shock.
- 1-2. Do not allow the terminals of a capacitor to come in contact with any conductive objects (short-circuit). Do not expose a capacitor to a conductive liquid, inducing any acid or alkali solutions.
- 1-3. Confirm the environment in which the equipment will operate is under the specified conditions.
  - Do not use the equipment under the following environments.
  - (1) Being spattered with water or oil.
  - (2) Being exposed to direct sunlight.
  - (3) Being exposed to ozone, ultraviolet rays, or radiation.
  - (4) Being exposed to toxic gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
  - (5) Any vibrations or mechanical shocks exceeding the specified limits.
  - (6) Moisture condensing environments.
- 1-4. Use damp proof countermeasures if using under any conditions that can cause condensation.

#### 2. Others

#### 2-1. In an Emergency

- (1) If the equipment should generate smoke, fire, or smell, immediately turn off or unplug the equipment. If the equipment is not turned off or unplugged, the hazards may be worsened by supplying continuous power.
- (2) In this type of situation, do not allow face and hands to come in contact with the capacitor or burns may be caused by the capacitor's high temperature.

#### 2-2. Disposal of waste

When capacitors are disposed of, they must be burned or buried by an industrial waste vendor with the appropriate licenses.

#### 2-3. Circuit Design

(1) Addition of Fail Safe Function

Capacitors that are cracked by dropping or bending of the board may cause deterioration of the insulation resistance, and result in a short. If the circuit being used may cause an electrical shock, smoke or fire when a capacitor is shorted, be sure to install fail-safe functions, such as a fuse, to prevent secondary accidents.

(2) This series are not safety standard certified products.

### 2-4. Remarks

Failure to follow the cautions may result, worst case, in a short circuit and smoking when the product is used. The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions.

Select optimum conditions for operation as they determine the reliability of the product after assembly.

The data herein are given in typical values, not guaranteed ratings.

# Rating

#### **1.Operating Temperature**

- 1. The operating temperature limit depends on the capacitor.
- 1-1. Do not apply temperatures exceeding the maximum operating temperature.

  It is necessary to select a capacitor with a suitable rated temperature that will cover the operating temperature range.

  It is also necessary to consider the temperature distribution in equipment and the seasonal temperature variable factor.
- 1-2. Consider the self-heating factor of the capacitor

  The surface temperature of the capacitor shall not exceed the maximum operating temperature including self-heating.

# 2.Atmosphere Surroundings (gaseous and liquid)

- 1. Restriction on the operating environment of capacitors.
- 1-1. Capacitors, when used in the above, unsuitable, operating environments may deteriorate due to the corrosion of the terminations and the penetration of moisture into the capacitor.
- 1-2. The same phenomenon as the above may occur when the electrodes or terminals of the capacitor are subject to moisture condensation.
- 1-3. The deterioration of characteristics and insulation resistance due to the oxidization or corrosion of terminal electrodes may result in breakdown when the capacitor is exposed to corrosive or volatile gases or solvents for long periods of time.

# 3.Piezo-electric Phenomenon

 When using high dielectric constant type capacitors in AC or pulse circuits, the capacitor itself vibrates at specific frequencies and noise may be generated.
 Moreover, when the mechanical vibration or shock is added to capacitor, noise may occur.

## Others

#### 1.Transportation

- 1. The performance of a capacitor may be affected by the conditions during transportation.
- 1-1. The capacitors shall be protected against excessive temperature, humidity and mechanical force during transportation.
  - (1) Climatic condition
    - · low air temperature : -40°C
    - · change of temperature air/air : -25°C/+25°C
    - · low air pressure : 30 kPa
    - · change of air pressure : 6 kPa/min.
  - (2) Mechanical condition

Transportation shall be done in such a way that the boxes are not deformed and forces are not directly passed on to the inner packaging.

- 1-2. Do not apply excessive vibration, shock, or pressure to the capacitor.
  - (1) When excessive mechanical shock or pressure is applied to a capacitor, chipping or cracking may occur in the ceramic body of the capacitor.
  - (2) When the sharp edge of an air driver, tweezers, a chassis, etc. impacts strongly on the surface of the capacitor, the capacitor may crack and short-circuit.
- 1-3. Do not use a capacitor to which excessive shock was applied by dropping etc. A capacitor dropped accidentally during processing may be damaged.

#### 2. Characteristics Evaluation in the Actual System

- 1. Evaluate the capacitor in the actual system,to confirm that there is no problem with the performance and specification values in a finished product before using.
- 2. Since a voltage dependency and temperature dependency exists in the capacitance of high dielectric type ceramic capacitors, the capacitance may change depending on the operating conditions in the actual system. Therefore, be sure to evaluate the various characteristics, such as the leakage current and noise absorptivity, which will affect the capacitance value of the capacitor.
- 3. In addition,voltages exceeding the predetermined surge may be applied to the capacitor by the inductance in the actual system. Evaluate the surge resistance in the actual system as required.



**⚠** NOTE

- 1.Please make sure that your product has been evaluated in view of your specifications with our product being mounted to your product.
- 2. Your are requested not to use our product deviating from this product specification.
- 3.We consider it not appropriate to include any terms and conditions with regard to the business transaction in the product specifications, drawings or other technical documents. Therefore, if your technical documents as above include such terms and conditions such as warranty clause, product liability clause, or intellectual property infringement liability clause, they will be deemed to be invalid.